

Vishay Siliconix

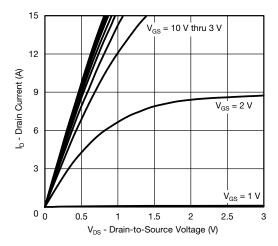
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static				•		
Drain-source breakdown voltage	V_{DS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	-30	-	-	V
V _{DS} temperature coefficient	$\Delta V_{DS}/T_{J}$	J 050 A	-	-23	-	mV/°C
V _{GS(th)} temperature coefficient	$\Delta V_{GS(th)}/T_J$	I _D = -250 μA	-	1.5	-	
Gate-source threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	-0.6	-	-1.1	V
Gate-source leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$	-	-	± 100	nA
Zero gate voltage drain current	l	$V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}$	1	-	-1	μΑ
zero gate voltage drain current	I _{DSS}	V_{DS} = -30 V, V_{GS} = 0 V, T_J = 55 °C	-	-	-10	
On-state drain current ^a	I _{D(on)}	$V_{DS} \le -5 \text{ V}, V_{GS} = -10 \text{ V}$	-10	-	-	Α
		$V_{GS} = -10 \text{ V}, I_D = -3 \text{ A}$	1	0.052	0.064	Ω
Drain-source on-state resistance ^a	R _{DS(on)}	$V_{GS} = -4.5 \text{ V}, I_D = -2 \text{ A}$	1	0.062	0.078	
		$V_{GS} = -2.5 \text{ V}, I_D = -1 \text{ A}$	-	0.090	0.120	
Forward transconductance ^a	g _{fs}	$V_{DS} = -15 \text{ V}, I_D = -3 \text{ A}$	1	10	-	S
Dynamic ^b						
Input capacitance	C _{iss}		ı	575	-	pF
Output capacitance	Coss	$V_{DS} = -15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	1	60	-	
Reverse transfer capacitance	C _{rss}		1	51	-	
Total gate charge	0	$V_{DS} = -15 \text{ V}, V_{GS} = -10 \text{ V}, I_D = -4.3 \text{ A}$	-	14	21	nC
Total gate charge	Q_g		-	6.6	10	
Gate-source charge	Q_{gs}	V_{DS} = -15 V, V_{GS} = -4.5 V, I_D = -4.3 A	-	1.2	-	
Gate-drain charge	Q_{gd}		-	1.9	-	
Gate resistance	R_g	f = 1 MHz	1.1	5.5	11	Ω
Turn-on delay time	t _{d(on)}		1	15	30	
Rise time	t _r	V_{DD} = -15 V, R_L = 4.4 Ω ,	-	18	35	
Turn-off delay time	t _{d(off)}	$I_D\cong$ -3.4 A, $V_{GEN}=$ -4.5 V, $R_g=$ 1 Ω	1	22	40	
Fall time	t _f	t _f		10	20	ns
Turn-on delay time	t _{d(on)}		ı	5	10	115
Rise time	t _r	V_{DD} = -15 V, R_L = 4.4 Ω ,	-	10	20	
Turn-off delay time	t _{d(off)}	$I_D \cong -3.4 \text{ A}, V_{GEN} = -10 \text{ V}, R_g = 1 \Omega$	-	22	40	
Fall time	t _f			10	20	
Drain-Source Body Diode Characterist	ics					
Continuous source-drain diode current	Is	T _C = 25 °C	-	-	-4.5	А
Pulse diode forward current	I _{SM}		-	-	-15	
Body diode voltage	V_{SD}	I _S = -3.4 A, V _{GS} = 0 V	-	-0.89	-1.2	V
Body diode reverse recovery time	t _{rr}		-	20	40	ns
Body diode reverse recovery charge	Q _{rr}	$I_F = -3.4 \text{ A}$, di/dt = 100 A/µs,	-	10	20	nC
Reverse recovery fall time	ta	$T_J = 25 ^{\circ}C$	-	9	-	ns
Reverse recovery rise time	t _b		-	11	_	

Notes

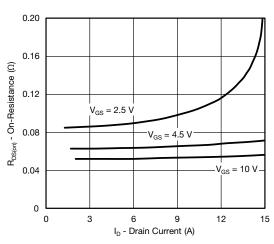
- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%$
- b. Guaranteed by design, not subject to production testing

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

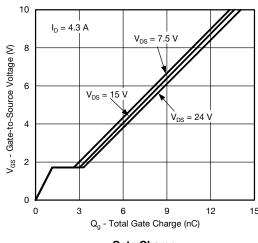




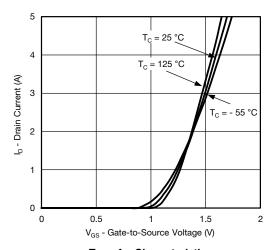
Output Characteristics



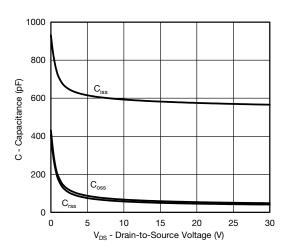
On-Resistance vs. Drain Current and Gate Voltage



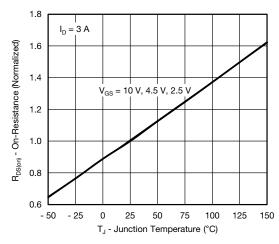
Gate Charge



Transfer Characteristics

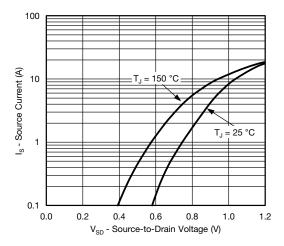


Capacitance

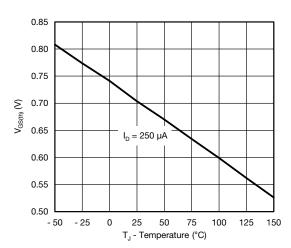


On-Resistance vs. Junction Temperature

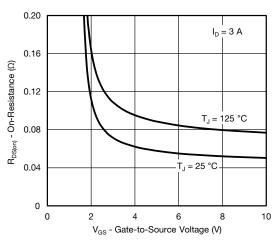




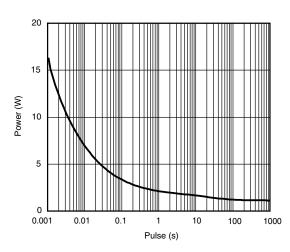
Source-Drain Diode Forward Voltage



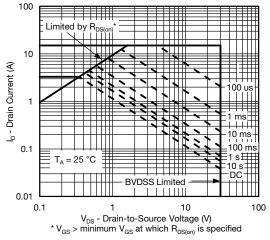
Threshold Voltage



On-Resistance vs. Gate-to-Source Voltage

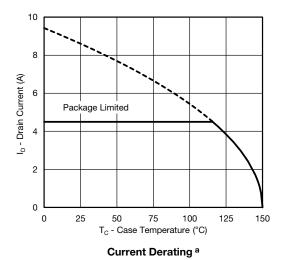


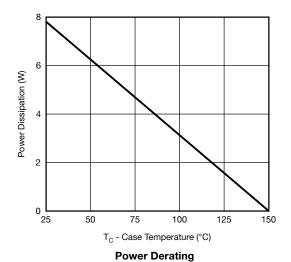
Single Pulse Power, Junction-to-Ambient



Safe Operating Area, Junction-to-Ambient



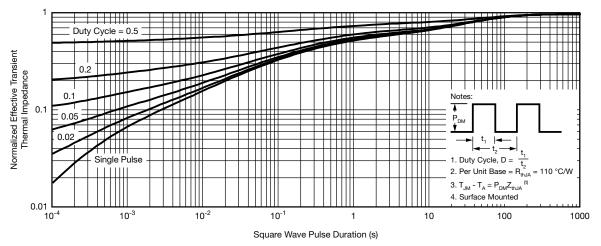




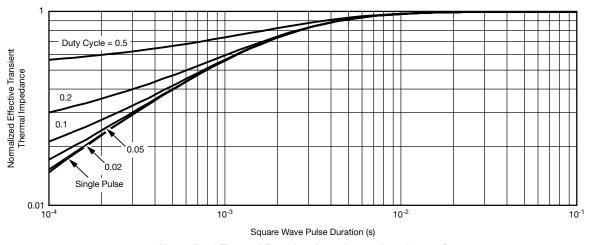
Note

a. The power dissipation P_D is based on T_J max. = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit





Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?63398.



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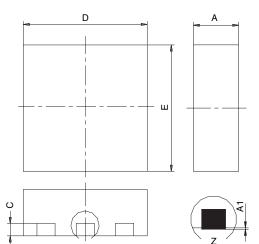
PowerPAK® SC70-6L





BACKSIDE VIEW OF SINGLE

BACKSIDE VIEW OF DUAL



- All dimensions are in millimeters
 Package outline exclusive of mold flash and metal burr
 Package outline inclusive of plating

DIM	SINGLE PAD						DUAL PAD						
	MILLIMETERS			INCHES			MILLIMETERS			INCHES			
	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	
Α	0.675	0.75	0.80	0.027	0.030	0.032	0.675	0.75	0.80	0.027	0.030	0.032	
A 1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002	
b	0.23	0.30	0.38	0.009	0.012	0.015	0.23	0.30	0.38	0.009	0.012	0.015	
С	0.15	0.20	0.25	0.006	0.008	0.010	0.15	0.20	0.25	0.006	0.008	0.010	
D	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085	
D1	0.85	0.95	1.05	0.033	0.037	0.041	0.513	0.613	0.713	0.020	0.024	0.028	
D2	0.135	0.235	0.335	0.005	0.009	0.013							
E	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085	
E1	1.40	1.50	1.60	0.055	0.059	0.063	0.85	0.95	1.05	0.033	0.037	0.041	
E2	0.345	0.395	0.445	0.014	0.016	0.018							
E3	0.425	0.475	0.525	0.017	0.019	0.021							
е	0.65 BSC		0.026 BSC		0.65 BSC			0.026 BSC					
K	0.275 TYP		0.011 TYP		0.275 TYP			0.011 TYP					
K1		0.400 TYP 0.016 TYP				0.320 TYP			0.013 TYP				
K2		0.240 TYP 0.009 TYP				0.252 TYP			0.010 TYP				
К3		0.225 TYP	1	0.009 TYP									
K4	0.355 TYP 0.014 TYP												
L	0.175	0.275	0.375	0.007	0.011	0.015	0.175	0.275	0.375	0.007	0.011	0.015	
Т							0.05	0.10	0.15	0.002	0.004	0.006	

DETAIL Z

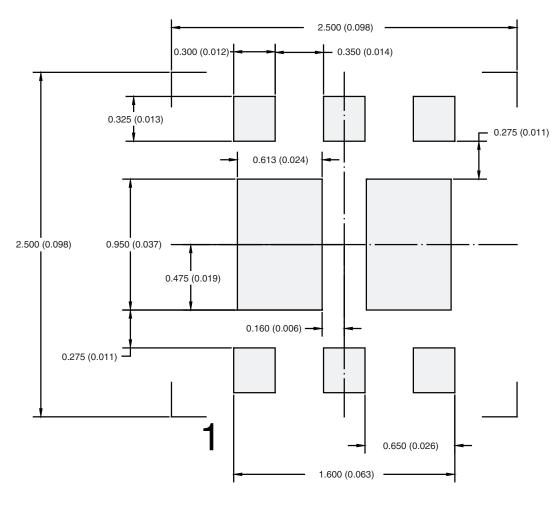
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RECOMMENDED PAD LAYOUT FOR PowerPAK® SC70-6L Dual



Dimensions in mm (inches)

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APPLICATION NOT

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Vishay

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